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## ISL9V2040D3S / ISL9V2040S3S / ISL9V2040P3

### EcoSPARK® 200mJ, 400V, N-Channel Ignition IGBT

#### General Description

The ISL9V2040D3S, ISL9V2040S3S, and ISL9V2040P3 are the next generation ignition IGBTs that offer outstanding SCIS capability in the space saving D-Pak (TO-252), as well as the industry standard D<sup>2</sup>-Pak (TO-263) and TO-220 plastic packages. This device is intended for use in automotive ignition circuits, specifically as a coil driver. Internal diodes provide voltage clamping without the need for external components.

EcoSPARK® devices can be custom made to specific clamp voltages. Contact your nearest Fairchild sales office for more information.

Formerly Developmental Type 49444

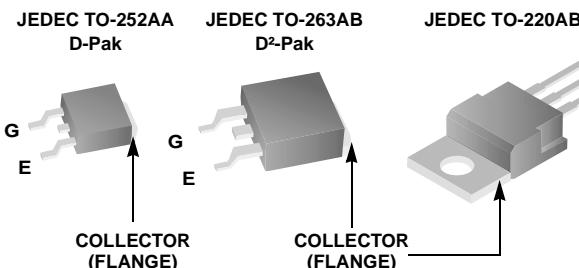
#### Applications

- Automotive Ignition Coil Driver Circuits
- Coil- On Plug Applications

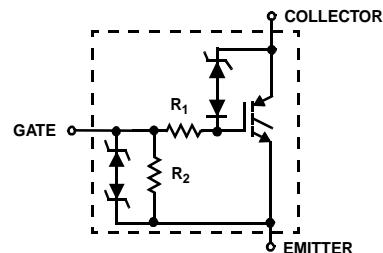
#### Features

- Space saving D - Pak package available
- SCIS Energy = 200mJ at  $T_J = 25^\circ\text{C}$
- Logic Level Gate Drive

#### Package



#### Symbol



#### Device Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$BV_{CER}$	Collector to Emitter Breakdown Voltage ( $I_C = 1\text{ mA}$ )	430	V
$BV_{ECS}$	Emitter to Collector Voltage - Reverse Battery Condition ( $I_C = 10\text{ mA}$ )	24	V
$E_{SCIS25}$	At Starting $T_J = 25^\circ\text{C}$ , $I_{SCIS} = 11.5\text{ A}$ , $L = 3.0\text{ mH}$	200	mJ
$E_{SCIS150}$	At Starting $T_J = 150^\circ\text{C}$ , $I_{SCIS} = 8.9\text{ A}$ , $L = 3.0\text{ mH}$	120	mJ
$I_{C25}$	Collector Current Continuous, At $T_C = 25^\circ\text{C}$ , See Fig 9	10	A
$I_{C110}$	Collector Current Continuous, At $T_C = 110^\circ\text{C}$ , See Fig 9	10	A
$V_{GEM}$	Gate to Emitter Voltage Continuous	$\pm 10$	V
$P_D$	Power Dissipation Total $T_C = 25^\circ\text{C}$	130	W
	Power Dissipation Derating $T_C > 25^\circ\text{C}$	0.87	W/ $^\circ\text{C}$
$T_J$	Operating Junction Temperature Range	-40 to 175	$^\circ\text{C}$
$T_{STG}$	Storage Junction Temperature Range	-40 to 175	$^\circ\text{C}$
$T_L$	Max Lead Temp for Soldering (Leads at 1.6mm from Case for 10s)	300	$^\circ\text{C}$
$T_{pkg}$	Max Lead Temp for Soldering (Package Body for 10s)	260	$^\circ\text{C}$
ESD	Electrostatic Discharge Voltage at 100pF, 1500 $\Omega$	4	kV

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
V2040D	ISL9V2040D3ST	TO-252AA	330mm	16mm	2500
V2040S	ISL9V2040S3ST	TO-263AB	330mm	24mm	800
V2040P	ISL9V2040P3	TO-220AB	Tube	N/A	50
V2040D	ISL9V2040D3S	TO-252AA	Tube	N/A	75
V2040S	ISL9V2040S3S	TO-263AB	Tube	N/A	50

## Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off State Characteristics

$BV_{CER}$	Collector to Emitter Breakdown Voltage	$I_C = 2\text{mA}$ , $V_{GE} = 0$ , $R_G = 1\text{K}\Omega$ , See Fig. 15 $T_J = -40$ to $150^\circ\text{C}$	370	400	430	V
$BV_{CES}$	Collector to Emitter Breakdown Voltage	$I_C = 10\text{mA}$ , $V_{GE} = 0$ , $R_G = 0$ , See Fig. 15 $T_J = -40$ to $150^\circ\text{C}$	390	420	450	V
$BV_{ECS}$	Emitter to Collector Breakdown Voltage	$I_C = -75\text{mA}$ , $V_{GE} = 0\text{V}$ , $T_C = 25^\circ\text{C}$	30	-	-	V
$BV_{GES}$	Gate to Emitter Breakdown Voltage	$I_{GES} = \pm 2\text{mA}$	$\pm 12$	$\pm 14$	-	V
$I_{CER}$	Collector to Emitter Leakage Current	$V_{CER} = 250\text{V}$ , $R_G = 1\text{K}\Omega$ , See Fig. 11	$T_C = 25^\circ\text{C}$ $T_C = 150^\circ\text{C}$	-	-	$25$ $\mu\text{A}$
$I_{ECS}$	Emitter to Collector Leakage Current	$V_{EC} = 24\text{V}$ , See Fig. 11	$T_C = 25^\circ\text{C}$ $T_C = 150^\circ\text{C}$	-	-	$1$ mA
$R_1$	Series Gate Resistance		-	70	-	$\Omega$
$R_2$	Gate to Emitter Resistance		10K	-	26K	$\Omega$

### On State Characteristics

$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	$I_C = 6\text{A}$ , $V_{GE} = 4\text{V}$	$T_C = 25^\circ\text{C}$ , See Fig. 3	-	1.45	1.9	V
$V_{CE(SAT)}$	Collector to Emitter Saturation Voltage	$I_C = 10\text{A}$ , $V_{GE} = 4.5\text{V}$	$T_C = 150^\circ\text{C}$ See Fig. 4	-	1.95	2.3	V

### Dynamic Characteristics

$Q_{G(ON)}$	Gate Charge	$I_C = 10\text{A}$ , $V_{CE} = 12\text{V}$ , $V_{GE} = 5\text{V}$ , See Fig. 14	-	12	-	nc	
$V_{GE(TH)}$	Gate to Emitter Threshold Voltage	$I_C = 1.0\text{mA}$ , $V_{CE} = V_{GE}$ , See Fig. 10	$T_C = 25^\circ\text{C}$	1.3	-	2.2	V
			$T_C = 150^\circ\text{C}$	0.75	-	1.8	V
$V_{GEP}$	Gate to Emitter Plateau Voltage	$I_C = 10\text{A}$ , $V_{CE} = 12\text{V}$	-	3.4	-	V	

### Switching Characteristics

$t_{d(ON)R}$	Current Turn-On Delay Time-Resistive	$V_{CE} = 14\text{V}$ , $R_L = 1\Omega$	-	0.61	-	$\mu\text{s}$
$t_{riseR}$	Current Rise Time-Resistive	$V_{CE} = 5\text{V}$ , $R_G = 1\text{K}\Omega$ $T_J = 25^\circ\text{C}$	-	2.17	-	$\mu\text{s}$
$t_{d(OFF)L}$	Current Turn-Off Delay Time-Inductive	$V_{CE} = 300\text{V}$ , $L = 500\mu\text{H}$ , $V_{GE} = 5\text{V}$ , $R_G = 1\text{K}\Omega$ $T_J = 25^\circ\text{C}$ , See Fig. 12	-	3.64	-	$\mu\text{s}$
$t_{fL}$	Current Fall Time-Inductive	$V_{CE} = 5\text{V}$ , $R_G = 1\text{K}\Omega$ $T_J = 25^\circ\text{C}$ , See Fig. 12	-	2.36	-	$\mu\text{s}$
SCIS	Self Clamped Inductive Switching	$T_J = 25^\circ\text{C}$ , $L = 3.0\text{mH}$ , $R_G = 1\text{K}\Omega$ , $V_{GE} = 5\text{V}$ , See Fig. 1 & 2	-	-	200	mJ

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction-Case	TO-252, TO-263, TO-220	-	-	1.15	$^\circ\text{C/W}$
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## Typical Performance Curves

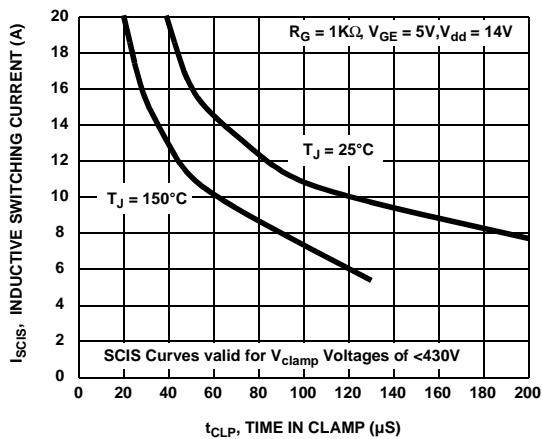


Figure 1. Self Clamped Inductive Switching Current vs Time in Clamp

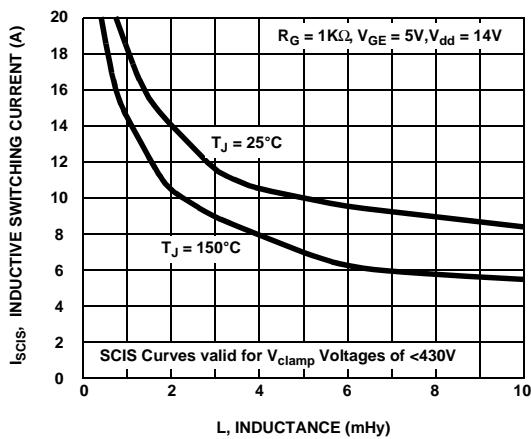


Figure 2. Self Clamped Inductive Switching Current vs Inductance

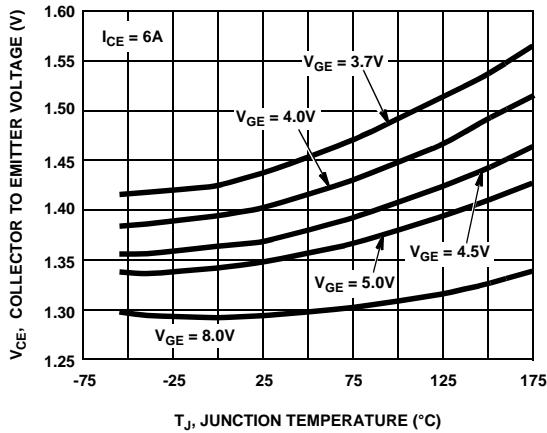


Figure 3. Collector to Emitter On-State Voltage vs Junction Temperature

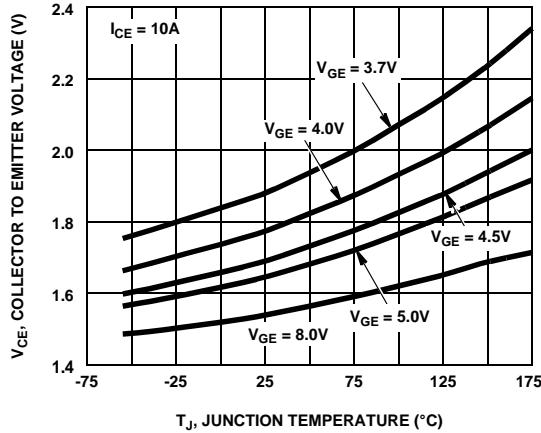


Figure 4. Collector to Emitter On-State Voltage vs Junction Temperature

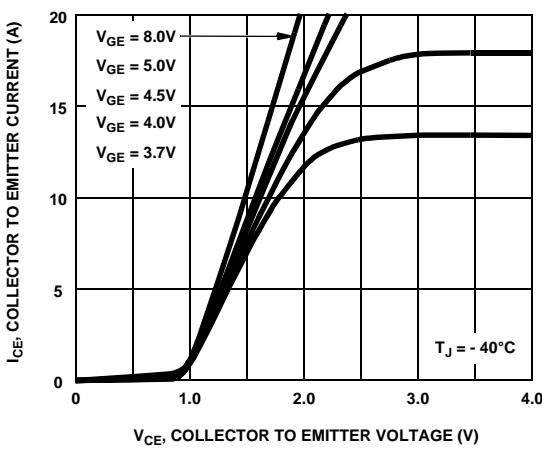


Figure 5. Collector to Emitter On-State Voltage vs Collector Current

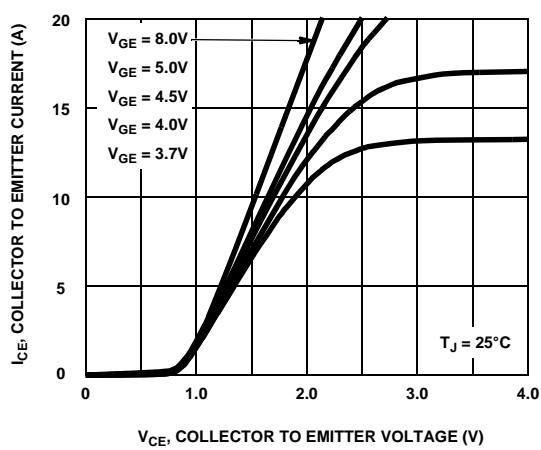
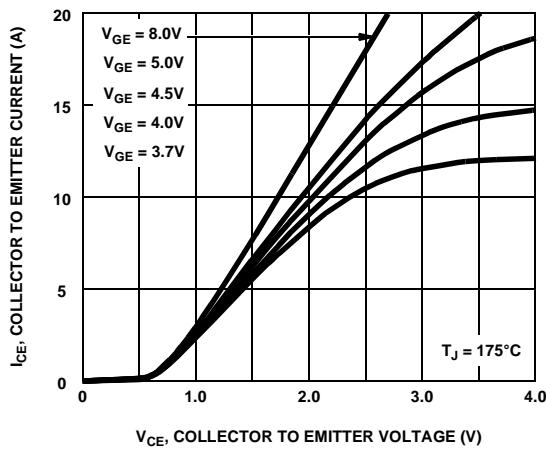
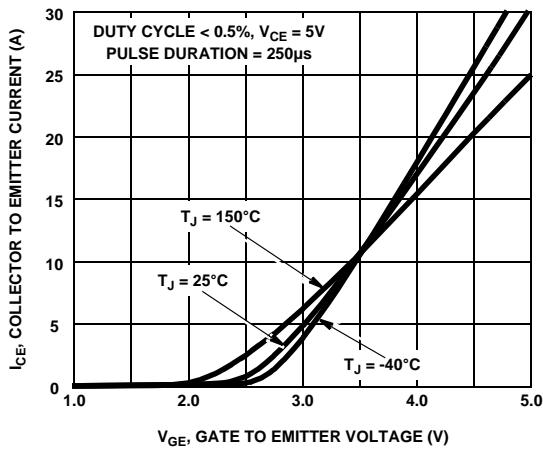


Figure 6. Collector to Emitter On-State Voltage vs Collector Current

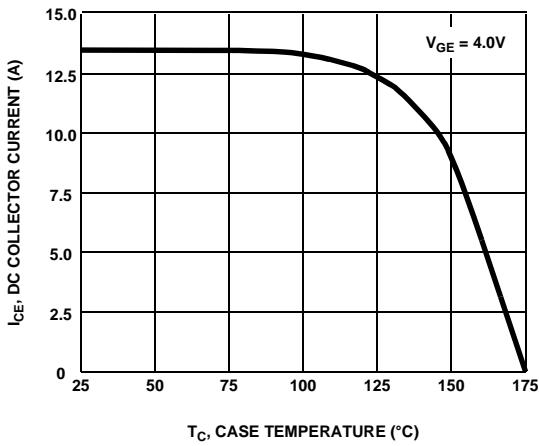
### Typical Performance Curves (Continued)



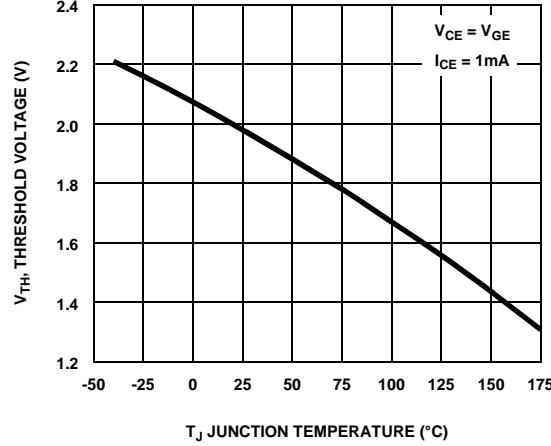
**Figure 7. Collector to Emitter On-State Voltage vs Collector Current**



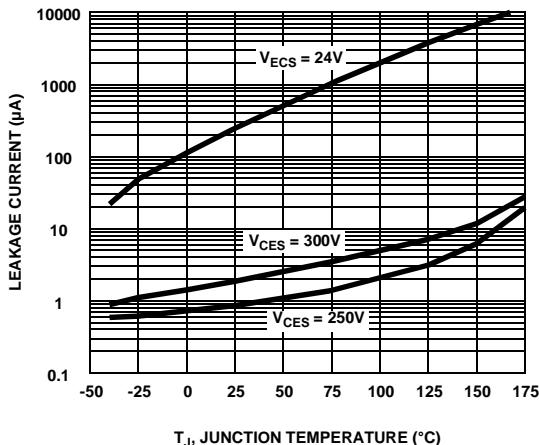
**Figure 8. Transfer Characteristics**



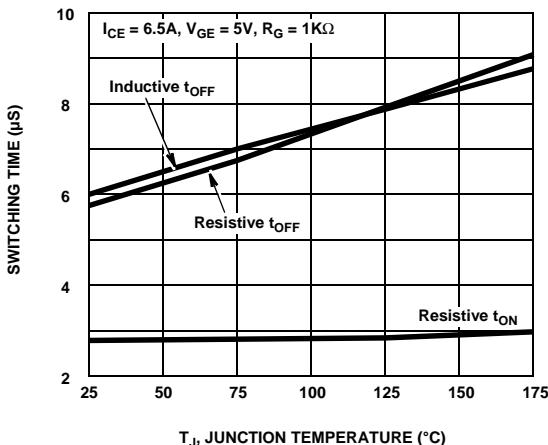
**Figure 9. DC Collector Current vs Case Temperature**



**Figure 10. Threshold Voltage vs Junction Temperature**



**Figure 11. Leakage Current vs Junction Temperature**



**Figure 12. Switching Time vs Junction Temperature**

### Typical Performance Curves (Continued)

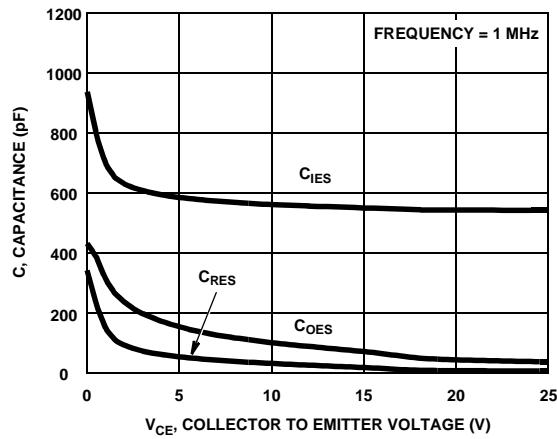


Figure 13. Capacitance vs "Collector to Emitter Voltage

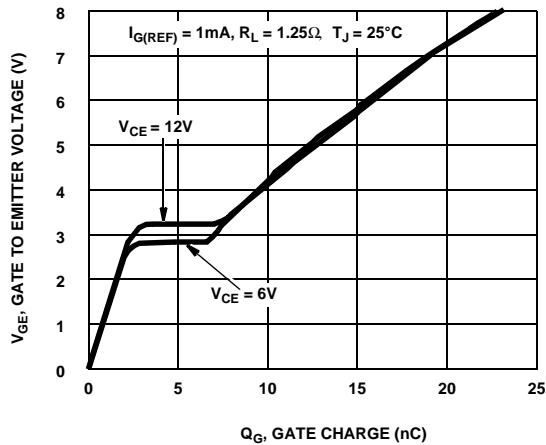


Figure 14. Gate Charge

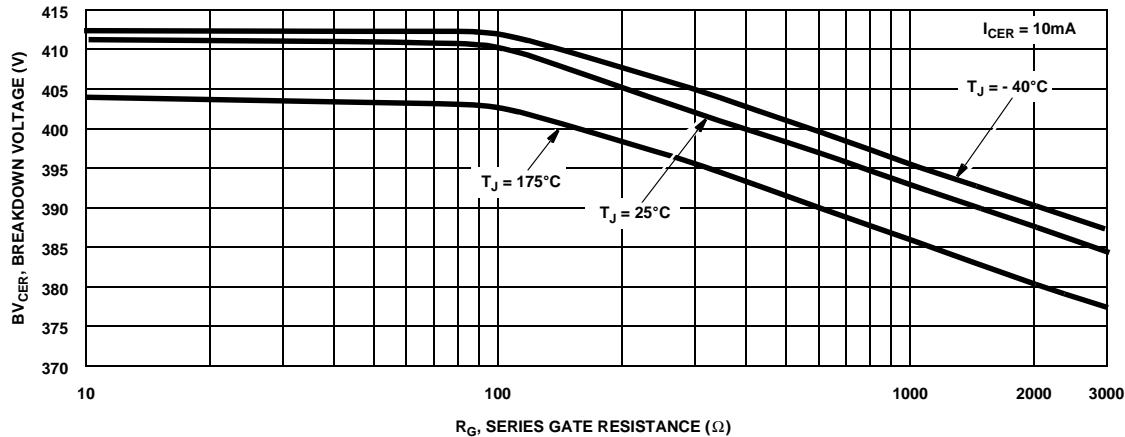


Figure 15. Breakdown Voltage vs "Series Gate Resistance

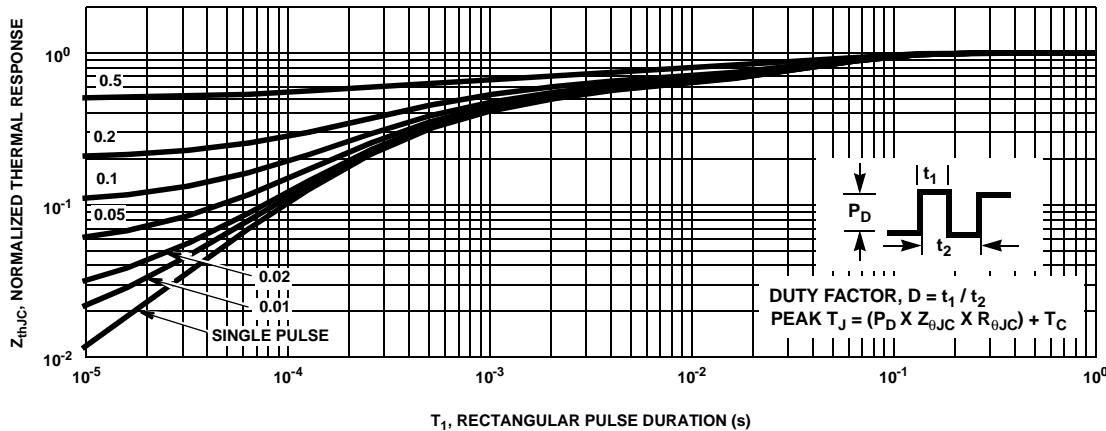


Figure 16. IGBT Normalized Transient Thermal Impedance, Junction to Case

### Test Circuit and Waveforms

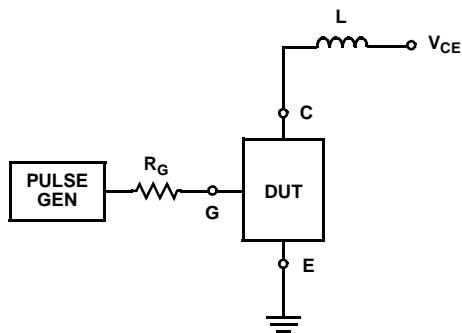


Figure 17. Inductive Switching Test Circuit

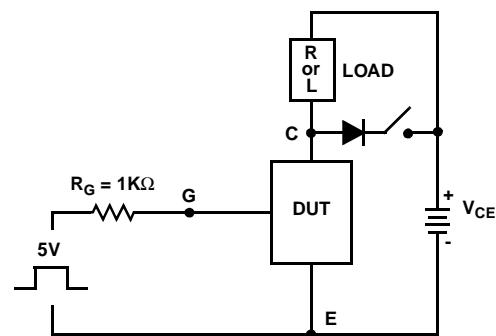


Figure 18.  $t_{ON}$  and  $t_{OFF}$  Switching Test Circuit

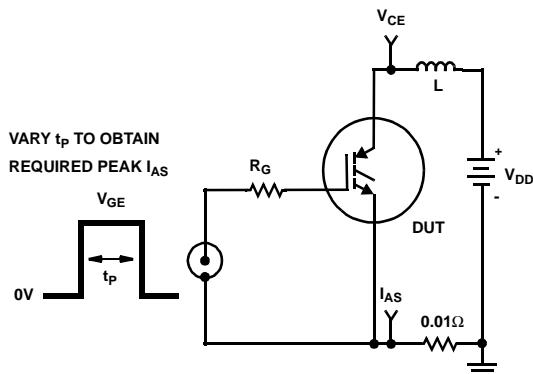


Figure 19. Unclamped Energy Test Circuit

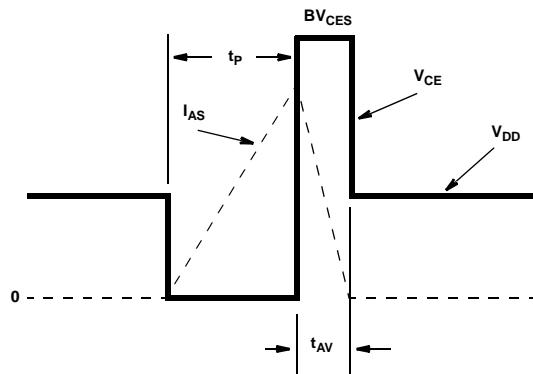


Figure 20. Unclamped Energy Waveforms

## SPICE Thermal Model

REV 25 April 2002

ISL9V2040D3S, ISL9V2040S3S, ISL9V2040P3

CTHERM1 th 6 1.3e -2  
 Ctherm2 6 5 8.8e -4  
 Ctherm3 5 4 8.8e -3  
 Ctherm4 4 3 3.9e -1  
 Ctherm5 3 2 3.6e -1  
 Ctherm6 2 tl 1.9e -1

Rtherm1 th 6 1.2e -1  
 Rtherm2 6 5 3.2e -1  
 Rtherm3 5 4 1.7e -1  
 Rtherm4 4 3 1.2e -1  
 Rtherm5 3 2 1.3e -1  
 Rtherm6 2 tl 2.5e -1

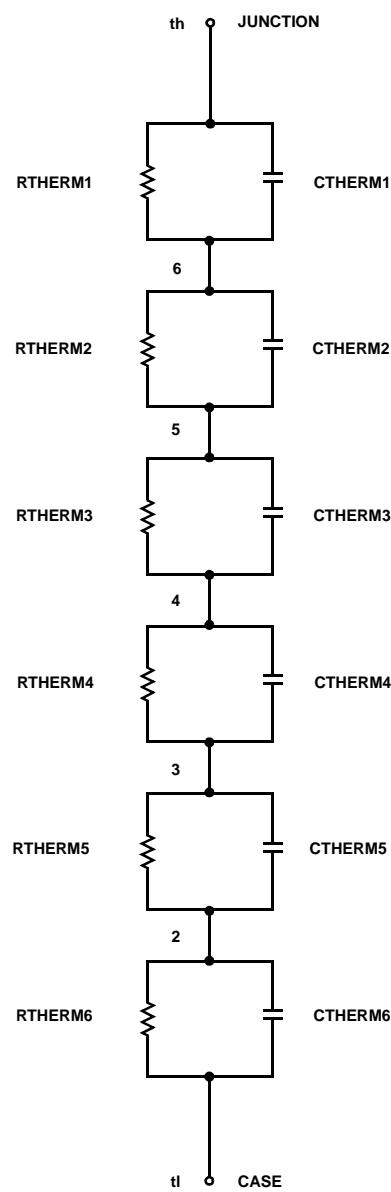
## SABER Thermal Model

SABER thermal model

ISL9V2040D3S, ISL9V2040S3S, ISL9V2040P3

```
template thermal_model th tl
thermal_c th, tl
{
    ctherm.ctherm1 th 6 = 1.3e -3
    ctherm.ctherm2 6 5 = 8.8e -4
    ctherm.ctherm3 5 4 = 8.8e -3
    ctherm.ctherm4 4 3 = 3.9e -1
    ctherm.ctherm5 3 2 = 3.6e -1
    ctherm.ctherm6 2 tl = 1.9e -1

    rtherm.rtherm1 th 6 = 1.2e -1
    rtherm.rtherm2 6 5 = 3.2e -1
    rtherm.rtherm3 5 4 = 1.7e -1
    rtherm.rtherm4 4 3 = 1.2e -1
    rtherm.rtherm5 3 2 = 1.3e -1
    rtherm.rtherm6 2 tl = 2.5e -1
}
```





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CTL™	GTO™	Saving our world, 1mW/W/kW at a time™	TinyPower™
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Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибуторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибуторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помочь разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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